## MPSW01, MPSW01A

## One Watt High Current Transistors

NPN Silicon

## Features

- $\mathrm{Pb}-$ Free Packages are Available*


## MAXIMUM RATINGS

\begin{tabular}{|c|c|c|c|}
\hline Rating \& Symbol \& Value \& Unit <br>
\hline $\begin{array}{lr}\text { Collector-Emitter Voltage } \\ & \text { MPSW01 } \\ \text { MPSW01A }\end{array}$ \& $\mathrm{V}_{\text {CEO }}$ \& $$
\begin{aligned}
& 30 \\
& 40
\end{aligned}
$$ \& Vdc <br>
\hline Collector-Base Voltage

MPSW01

MPSW01A \& $\mathrm{V}_{\text {CBO }}$ \& $$
\begin{aligned}
& 40 \\
& 50
\end{aligned}
$$ \& Vdc <br>

\hline Emitter-Base Voltage \& $\mathrm{V}_{\text {Ebo }}$ \& 5.0 \& Vdc <br>
\hline Collector Current - Continuous \& $\mathrm{I}_{\mathrm{C}}$ \& 1000 \& mAdc <br>

\hline Total Device Dissipation @ $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ Derate above $25^{\circ} \mathrm{C}$ \& $\mathrm{P}_{\mathrm{D}}$ \& \[
$$
\begin{aligned}
& 1.0 \\
& 8.0
\end{aligned}
$$

\] \& \[

$$
\begin{gathered}
\mathrm{W} \\
\mathrm{~mW} /{ }^{\circ} \mathrm{C}
\end{gathered}
$$
\] <br>

\hline Total Device Dissipation @ $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ Derate above $25^{\circ} \mathrm{C}$ \& $\mathrm{P}_{\mathrm{D}}$ \& \[
$$
\begin{aligned}
& 2.5 \\
& 20
\end{aligned}
$$

\] \& \[

$$
\begin{gathered}
\mathrm{W} \\
\mathrm{~mW} /{ }^{\circ} \mathrm{C}
\end{gathered}
$$
\] <br>

\hline Operating and Storage Junction Temperature Range \& $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {stg }}$ \& -55 to +150 \& ${ }^{\circ} \mathrm{C}$ <br>
\hline
\end{tabular}

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
| :--- | :---: | :---: | :---: |
| Thermal Resistance, Junction-to-Ambient | $\mathrm{R}_{\theta \mathrm{JA}}$ | 125 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, Junction-to-Case | $\mathrm{R}_{\theta \mathrm{JC}}$ | 50 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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EMITTER


STRAIGHT LEAD BULK PACK


TO-92 1 WATT
(TO-226) CASE 29-10 STYLE 1

BENT LEAD TAPE \& REEL AMMO PACK

MARKING DIAGRAM


$$
\begin{array}{ll}
\text { X } & =01 \text { A Devices } \\
\text { A } & =\text { Assembly Location } \\
\text { Y } & =\text { Year } \\
\text { WW } & =\text { Work Week } \\
\text { - } & =\text { Pb-Free Package }
\end{array}
$$

(Note: Microdot may be in either location)
ORDERING INFORMATION
See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Characteristic |  | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |  |
| Collector-Emitter Breakdown Voltage (Note 1) ( $\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=0$ ) | MPSW01 MPSW01A | $V_{\text {(BR) }}$ CEO | $\begin{aligned} & 30 \\ & 40 \end{aligned}$ | - | Vdc |
| Collector-Base Breakdown Voltage ( $\mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{Adc}, \mathrm{I}_{\mathrm{E}}=0$ ) | MPSW01 MPSW01A | $V_{(B R)}$ cBo | $\begin{aligned} & 40 \\ & 50 \end{aligned}$ | - | Vdc |
| Emitter-Base Breakdown Voltage ( $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{Adc}$, $\mathrm{I}_{\mathrm{C}}=0$ ) |  | $\mathrm{V}_{(\mathrm{BR}) \mathrm{EBO}}$ | 5.0 | - | Vdc |
| Collector Cutoff Current $\begin{aligned} & \left(\mathrm{V}_{\mathrm{CB}}=30 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0\right) \\ & \left(\mathrm{V}_{\mathrm{CB}}=40 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0\right) \\ & \hline \end{aligned}$ | $\begin{array}{r} \text { MPSW01 } \\ \text { MPSW01A } \end{array}$ | ICBO | - | $\begin{aligned} & 0.1 \\ & 0.1 \end{aligned}$ | $\mu \mathrm{Adc}$ |
| Emitter Cutoff Current ( $\left.\mathrm{V}_{\mathrm{EB}}=3.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0\right)$ |  | $\mathrm{I}_{\text {EBO }}$ | - | 0.1 | $\mu \mathrm{Adc}$ |

ON CHARACTERISTICS (Note 1)

| $\begin{aligned} & \text { DC Current Gain } \\ & \begin{array}{l} \left(I_{C}=10 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}\right) \\ \left(\mathrm{I}_{\mathrm{C}}=100 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}\right) \\ \left(\mathrm{I}_{\mathrm{C}}=1000 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}\right) \end{array} \end{aligned}$ | $\mathrm{h}_{\text {FE }}$ | $\begin{aligned} & 55 \\ & 60 \\ & 50 \end{aligned}$ |  | - |
| :---: | :---: | :---: | :---: | :---: |
| Collector-Emitter Saturation Voltage ( $\mathrm{I}_{\mathrm{C}}=1000 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=100 \mathrm{mAdc}$ ) | $\mathrm{V}_{\text {CE(sat) }}$ | - | 0.5 | Vdc |
| Base-Emitter On Voltage ( $\mathrm{I}_{\mathrm{C}}=1000 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}$ ) | $\mathrm{V}_{\text {BE(on) }}$ | - | 1.2 | Vdc |

SMALL-SIGNAL CHARACTERISTICS

| Current-Gain — Bandwidth Product $\left(\mathrm{I}_{\mathrm{C}}=50 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{f}=20 \mathrm{MHz}\right)$ | $\mathrm{f}_{\mathrm{T}}$ | 50 | - | MHz |
| :--- | :---: | :---: | :---: | :---: |
| Output Capacitance $\left(\mathrm{V}_{\mathrm{CB}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ | $\mathrm{C}_{\mathrm{obo}}$ | - | 20 | pF |

1. Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 2.0 \%$.

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| MPSW01 | TO-92 | 5000 Units / Bulk |
| MPSW01G | TO-92 <br> (Pb-Free) | 5000 Units / Bulk |
| MPSW01AG | TO-92 <br> (Pb-Free) | 5000 Units / Bulk |
| MPSW01ARLRAG | TO-92 <br> (Pb-Free) | $2000 /$ Tape \& Reel |
| MPSW01ARLRPG | TO-92 <br> (Pb-Free) | $2000 /$ Tape \& Ammo Box |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



Figure 3. "ON" Voltages


Figure 4. Temperature Coefficient

Figure 5. Current Gain - Bandwidth Product



Figure 6. Capacitance


Figure 7. Active Region - Safe Operating Area


STRAIGHT LEAD


BENT LEAD

TO-92 (TO-226) 1 WATT
CASE 29-10 ISSUE A

DATE 08 MAY 2012


NOTES:
. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1994.
CONTOUR OF PACKAGE BEYOND DIMENSION RIS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN DIMENSIONS $P$ DIMENSION F APPLIES BETWEEN DIMENSIONS P
AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

|  | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | MAX | MIN | MAX |
| A | 0.175 | 0.20 | 4.44 | 5.21 |
| B | 0.290 | 0.310 | 7.37 | 7.87 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.018 | 0.021 | 0.46 | 0.53 |
| F | 0.016 | 0.019 | 0.41 | 0.48 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| H | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.018 | 0.024 | 0.46 | 0.61 |
| K | 0.500 | --- | 12.70 | --- |
| L | 0.050 | -- | 6.35 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | --- | 2.54 |
| R | 0.135 | --- | 3.43 | --- |
| V | 0.135 | --- | 3.43 | --- |

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
CONTOUR OF PACKAGE BEYOND DIMENSION RIS CONTOUR OF PAC
2. DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS LAND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

|  | INCHES |  |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | MAX | MIN | MAX |  |
| A | 0.175 | 0.205 | 4.44 | 5.21 |  |
| B | 0.290 | 0.310 | 7.37 | 7.87 |  |
| C | 0.125 | 0.165 | 3.18 | 4.19 |  |
| D | 0.018 | 0.021 | 0.46 | 0.53 |  |
| G | 0.094 | 0.102 | 2.40 | 2.80 |  |
| J | 0.018 | 0.024 | 0.46 | 0.61 |  |
| K | 0.500 | -- | 12.70 | --- |  |
| N | 0.080 | 0.105 | 2.04 | 2.66 |  |
| P | --- | 0.100 | --- | 2.54 |  |
| R | 0.135 | -- | 3.33 | --- |  |
| $\mathbf{V}$ | 0.135 | --- | 3.43 | --- |  |

STYLES ON PAGE 2

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| DESCRIPTION: | TO-92 (TO-226) 1 WATT | PAGE 1 OF 3 |

## TO-92 (TO-226) 1 WATT

CASE 29-10 ISSUE A

| STYLE 1: |  |
| :---: | :---: |
| PIN 1. | Emitter |
| 2. | BASE |
| 3. | COLLECTOR |
| STYLE 6: |  |
| PIN 1. | GATE |
| 2. | SOURCE \& SUBSTRATE |
| 3. | DRAIN |
| STYLE 11: |  |
| PIN 1. | ANODE |
| 2. | CATHODE \& ANODE |
| 3. | CATHODE |
| STYLE 16: |  |
| PIN 1. | ANODE |
| 2. | GATE |
| 3. | CATHODE |
| STYLE 21: |  |
| PIN 1. | COLLECTOR |
| 2. | Emitter |
| 3. | BASE |
| STYLE 26: |  |
| PIN 1. | $V_{C C}$ |
| 2. | GROUND 2 |
| 3. | OUTPUT |
| STYLE 31: |  |
| PIN 1. | GATE |
| 2. | DRAIN |
| 3. | SOURCE |


| STYLE 2: |  |
| :--- | :--- |
| PIN 1. | BASE |
| 2. | EMITTER |
| 3. | COLLECTOR |
| STYLE 7: |  |
| PIN 1. | SOURCE |
| 2. | DRAIN |
| 3. | GATE |
| STYLE 12: |  |
| PIN 1. | MAIN TERMINAL 1 |
| 2. | GATE |
| 3. | MAIN TERMINAL 2 |
| STYLE 17: |  |
| PIN 1. | COLLECTOR |
| 2. | BASE |
| 3. | EMITTER |
| STYLE 22: |  |
| PIN 1. | SOURCE |
| 2. | GATE |
| 3. | DRAIN |
| STYLE 27: |  |
| PIN 1. | MT |
| 2. | SUBSTRATE |
| 3. | MT |
| STYLE 32: |  |
| PIN 1. | BASE |
| 2. | COLLECTOR |
| 3. | EMITTER |


| STYLE 3: |  |
| :--- | :--- |
| PIN 1. | ANODE |
| 2. | ANODE |
| 3. | CATHODE |
| STYLE 8: |  |
| PIN 1. | DRAIN |
| 2. | GATE |
| 3. | SOURCE \& SUBSTRATE |
| STYLE 13: |  |
| PIN 1. | ANODE 1 |
| 2. | GATE |
| 3. | CATHODE 2 |
| STYLE 18: |  |
| PIN 1. | ANODE |
| 2. | CATHODE |
| 3. | NOT CONNECTED |
| STYLE 23: |  |
| PIN 1. | GATE |
| 2. | SOURCE |
| 3. | DRAIN |
| STYLE 28: |  |
| PIN 1. | CATHODE |
| 2. | ANODE |
| 3. | GATE |
| STYLE 33: |  |
| PIN 1. | RETURN |
| 2. | INPUT |
| 3. |  |


| STYLE 4: |  | STYLE 5: |  |
| :---: | :---: | :---: | :---: |
| PIN 1. | CATHODE | PIN 1. | DRAIN |
| 2. | CATHODE | 2. | SOURCE |
| 3. | ANODE | 3. | GATE |
| STYLE 9: |  | STYLE 10: |  |
| PIN 1. | BASE 1 | PIN 1. | CATHODE |
| 2. | EMITTER | 2. | GATE |
| 3. | BASE 2 | 3. | ANODE |
| STYLE 14: |  | STYLE 15: |  |
| PIN 1. | Emitter | PIN 1. | ANODE 1 |
| 2. | COLLECTOR | 2. | CATHODE |
| 3. | BASE | 3. | ANODE 2 |
| STYLE 19: |  | STYLE 20: |  |
| PIN 1. | GATE | PIN 1. | NOT CONNECTED |
| 2. | ANODE | 2. | CATHODE |
| 3. | CATHODE | 3. | ANODE |
| STYLE 24: |  | STYLE 25: |  |
| PIN 1. | Emitter | PIN 1. | MT 1 |
| 2. | COLLECTOR/ANODE | 2. | GATE |
| 3. | CATHODE | 3. | MT 2 |
| STYLE 29: |  | STYLE 30: |  |
| PIN 1. | NOT CONNECTED | PIN 1. | DRAIN |
| 2. | ANODE | 2. | GATE |
| 3. | CATHODE | 3. | SOURCE |
| STYLE 34: |  | STYLE 35: |  |
| PIN 1. | INPUT | PIN 1. | GATE |
| 2. | GROUND | 2. | COLLECTOR |
|  | LOGIC | 3. | EMITTER |


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